## NSN 5962-00-547-2651

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-547-2651 **Body Length:** Between 0.735 inches and 0.830 inches **Body Width:** Between 0.260 inches and 0.293 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 350.0 milliwatts **Operating Tempurature Range:** +0.0 to 75.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Diode-transistor logic and transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 55.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

Fiig:

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